## Fast Soft Recovery Rectifier Diode, 20 A



## PRODUCT SUMMARY

| $\mathrm{V}_{\mathrm{F}}$ at 10 A | $<1.2 \mathrm{~V}$ |
| :---: | :---: |
| $\mathrm{I}_{\text {FSM }}$ | 300 A |
| $\mathrm{~V}_{\text {RRM }}$ | 200 V to 600 V |

## FEATURES

- The fully isolated package $\left(\mathrm{V}_{\text {INS }}=2500 \mathrm{~V}_{\mathrm{RMS}}\right)$ is UL E78996 approved
-1
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level


## APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met


## DESCRIPTION

The 20ETF..FPPbF soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.
The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS

| SYMBOL | CHARACTERISTICS | VALUES | UNITS |
| :--- | :--- | :---: | :---: |
| $\mathrm{I}_{\text {F(AV }}$ | Sinusoidal waveform | 20 | A |
| $\mathrm{~V}_{\text {RRM }}$ |  | 200 to 600 | V |
| $\mathrm{I}_{\text {FSM }}$ |  | 300 | A |
| $\mathrm{~V}_{\mathrm{F}}$ | $10 \mathrm{~A}, \mathrm{~T}_{J}=25^{\circ} \mathrm{C}$ | 1.2 | V |
| $\mathrm{t}_{\mathrm{rr}}$ | $1 \mathrm{~A}, 100 \mathrm{~A} / \mu \mathrm{s}$ | 60 | ns |
| $\mathrm{~T}_{J}$ |  | -40 to 150 | ${ }^{\circ} \mathrm{C}$ |

VOLTAGE RATINGS

| PART NUMBER | $V_{\text {RRM, }}$, MAXIMUM PEAK REVERSE VOLTAGE v | V $_{\text {RSM, }}$, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | $\begin{gathered} \mathrm{I}_{\mathrm{RRM}} \\ \text { AT } 150{ }^{\circ} \mathrm{C} \\ \mathrm{~mA} \end{gathered}$ |
| :---: | :---: | :---: | :---: |
| 20ETF02FPPbF | 200 | 300 | 5 |
| 20ETF04FPPbF | 400 | 500 |  |
| 20ETF06FPPbF | 600 | 700 |  |

ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: |
| Maximum average forward current | $\mathrm{I}_{\text {F(AV) }}$ | $\mathrm{T}_{\mathrm{C}}=94^{\circ} \mathrm{C}, 180^{\circ}$ conduction half sine wave | 20 | A |
| Maximum peak one cycle non-repetitive surge current | $\mathrm{I}_{\text {FSM }}$ | 10 ms sine pulse, rated $\mathrm{V}_{\text {RRM }}$ applied | 250 |  |
|  |  | 10 ms sine pulse, no voltage reapplied | 300 |  |
| Maximum $\mathrm{I}^{2} \mathrm{t}$ for fusing | ${ }^{2} \mathrm{t}$ | 10 ms sine pulse, rated $\mathrm{V}_{\text {RRM }}$ applied | 316 | $A^{2} \mathrm{~s}$ |
|  |  | 10 ms sine pulse, no voltage reapplied | 442 |  |
| Maximum $I^{2} \sqrt{ }$ t for fusing | $\mathrm{I}^{2} \sqrt{ } \mathrm{t}$ | $\mathrm{t}=0.1 \mathrm{~ms}$ to 10 ms , no voltage reapplied | 4420 | $A^{2} \sqrt{ } \mathrm{~s}$ |

* Pb containing terminations are not RoHS compliant, exemptions may apply


## 20ETF..FPPbF Soft Recovery Series

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| ELECTRICAL SPECIFICATIONS |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | TEST CONDITIONS |  | VALUES | UNITS |
| Maximum forward voltage drop | $V_{\text {FM }}$ | $20 \mathrm{~A}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 1.30 | V |
|  |  | $60 \mathrm{~A}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 1.67 |  |
| Forward slope resistance | $r_{\text {t }}$ |  |  | 12.5 | $\mathrm{m} \Omega$ |
| Threshold voltage | $\mathrm{V}_{\mathrm{F} \text { (TO) }}$ | $\mathrm{T}_{J}=150^{\circ} \mathrm{C}$ |  | 0.9 | V |
| Maximum reverse leakage current |  | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | $V_{\text {R }}=$ Rated $V_{\text {RRM }}$ | 0.1 | mA |
| Maximum reverse leakage current | IRM | $\mathrm{T}_{\mathrm{J}}=150^{\circ} \mathrm{C}$ | VRM | 5.0 |  |


| RECOVERY CHARACTERISTICS |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |  |
| Reverse recovery time | $\mathrm{t}_{\text {rr }}$ | $\mathrm{I}_{\mathrm{F}}$ at 20 Apk $100 \mathrm{~A} / \mu \mathrm{s}$ $25^{\circ} \mathrm{C}$ | 160 | ns |  |
| Reverse recovery current | $I_{\text {rr }}$ |  | 10 | A |  |
| Reverse recovery charge | $\mathrm{Q}_{\mathrm{rr}}$ |  | 1.25 | $\mu \mathrm{C}$ |  |
| Snap factor | S | Typical | 0.6 |  |  |


| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: |
| Maximum junction and storage temperature range | $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\text {Stg }}$ |  | - 40 to 150 | ${ }^{\circ} \mathrm{C}$ |
| Maximum thermal resistance, junction to case | $\mathrm{R}_{\text {thJc }}$ | DC operation | 1.5 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Maximum thermal resistance, junction to ambient | $\mathrm{R}_{\text {thJA }}$ |  | 62 |  |
| Typical thermal resistance, case to heatsink | $\mathrm{R}_{\text {thcs }}$ | Mounting surface, smooth and greased | 1.5 |  |
| Approximate weight |  |  | 2 | 9 |
|  |  |  | 0.07 | oz. |
| Mounting torque $\quad$minimum <br>  |  |  | 6 (5) | $\mathrm{kgf} \cdot \mathrm{cm}$ (lbf • in) |
|  |  |  | 12 (10) |  |
| Marking device |  | Case style TO-220 FULL-PAK | 20ETF02FP |  |
|  |  |  | 20ETF04FP |  |
|  |  |  | 20ETF06FP |  |

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Fig. 1 - Current Rating Characteristics


Fig. 2 - Current Rating Characteristics


Fig. 3 - Forward Power Loss Characteristics


Fig. 4 - Forward Power Loss Characteristics
 Current Pulses ( N )
Fig. 5 - Maximum Non-Repetitive Surge Current


Fig. 6 - Maximum Non-Repetitive Surge Current

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Fig. 7 - Forward Voltage Drop Characteristics


Fig. 8 - Recovery Time Characteristics, $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$


Fig. 9 - Recovery Time Characteristics, $\mathrm{T}_{J}=150^{\circ} \mathrm{C}$


Fig. 10 - Recovery Charge Characteristics, $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$


Fig. 11 - Recovery Charge Characteristics, $T_{J}=150^{\circ} \mathrm{C}$


Fig. 12 - Recovery Current Characteristics, $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$

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Fig. 13 - Recovery Current Characteristics, $\mathrm{T}_{J}=150^{\circ} \mathrm{C}$


Fig. 14 - Thermal Impedance $Z_{\text {thJc }}$ Characteristics

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## ORDERING INFORMATION TABLE



## DIMENSIONS in millimeters



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[^0]:    Lead assignments
    Diodes
    1+2-Cathode
    3 - Anode

    Conforms to JEDEC outline TO-220 FULL-PAK

